

Features

- Frequency Range DC-14GHz
- 51.5dBm Nominal P_{3dB} Pulsed
- Maximum PAE at 6GHz of 71%
- 18dB Linear Gain at 6GHz
- Drain Bias 28V
- Technology: GaN on SiC
- Lead-free and RoHS compliant
- Chip Dimensions: 0.82 x 4.56 x 0.10mm

Applications

- Aerospace & Defense
- Broadband Wireless

Description

The ICPB1020 is a GaN on SiC discrete HEMT that operates from DC-14GHz. The design is optimized for power and efficiency using field plate technology.



RF Performance | Simulated Conditions unless otherwise stated | T_A=25°C, V_D=28V, Pulse Width 100uS, Duty Cycle=10%

Parameter	Units	Typical			
Frequency	GHz	3	6	10	14
Output Power P _{3dB}	dB	51.6	51.6	51.6	51.6
Bias Current	mA	400	400	400	400
PAE @ P _{3dB}	%	77.7	71.4	64.4	55.7
Gain @ P _{3dB}	dB	21	15	10.1	7.4

Image

Recommended operating conditions

Parameter	Value
Drain Voltage (V _{DG})	12-32 V
Drain Quiescent Current (I _D)	0.4-1A
Drain current RF Drive (I_D)	8A
Gate Voltage (V _G)	-3V
Power Dissipation (CW)	112W
Channel Temperature (Max)	225°C

Absolute Maximum Ratings

Parameter	Absolute Maximum
Drain to Gate Voltage (V_{DG})	80 V
Gate Voltage Range (V _G)	-20V to 0V
Gate Current (I _G)	-20 to 60mA
Power Dissipation (CW)	128W
CW Input Power	+43dBm
Channel Temperature	275°C
Storage Temperature	-65°C to +150°C

Exceeding any one or combination of these limits may cause permanent damage to this device. ICONIC RF does not recommend sustained operation near

these survivability limits.



Thermal and Reliability





Notes

- Assumes silver sintered epoxy attach (15um thick) and mounted on CuMo carrier 1.
- Base temperature is assumed at the top of the CuMo carrier 2.



Model S-parameters | T_A = 25°C





Model Load Pull Data 3GHz



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Model Load Pull Data 6GHz



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Model Load Pull Data 10GHz



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Model Load Pull Data 14GHz



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Mechanical Drawing



Bond Pads

Pad Number	Description	Dimensions (mm)	
1,18	Gate Resistor	0.137 x 0.870	
2-17	Gate	0.137 x 0.147	
19, 23	Source	0.07 x 0.062	
20,22	Drain Resistor	0.137 x 0.087	
21	Drain	4.17 x 0.137	
Die Backside	Source	4.562 x 0.824	

Bias-Up Procedure

- Set V_G=-5V 1.
- Set V_D to 28V 2.
- 3. Adjust V_G positive until ID quiescent achieved
- Limit I_D to 8A 4.
- Apply RF Signal 5.

Bias-down Procedure

- Turn off RF 1.
- Turn off V_D, allow drain capacitor to discharge 2.
- Turn off V_G. 3.

Assembly Guidance

Die attach of component using adhesive

- Vacuum collets are preferred method of pickup
- Silver sintered epoxy is recommended -Namics • H9890-6A, Kyocera CT2700R7S

Die attach of component using Eutectic

- Flux-less gold-tin (AuSn) (80% Au, 20% Sn with • a melting point of 280°C) preform is preferred between the die and attached surface.
- Recommended preform should be approximately • 0.0012" thick.
- Die bonder using heated collet with a temperature of 310°C and die scrubbing should be used to ensure wetting and prevent formation of voids.
- Exposure to extreme temperature should be • kept to a minimum.
- The optimum die attach environment is nitrogen atmosphere.

Interconnect assembly Notes

- Ball Bonding and wedge bonding is preferred technique
- Force, time and ultrasonic parameters are critical .
- Aluminum wire bonding is not recommended
- Bond Wire diameter of 1.5mil is recommended

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.



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